

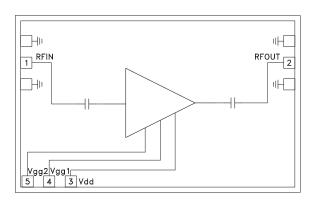
# GaAs HEMT MMIC LOW NOISE AMPLIFIER, 1 - 12 GHz

# **Typical Applications**

This HMC-ALH444 is ideal for:

- Wideband Communication Systems
- Surveillance Systems
- · Point-to-Point Radios
- · Point-to-Multi-Point Radios
- Military & Space
- Test Instrumentation
- \* VSAT

#### **Functional Diagram**



#### **Features**

Noise Figure: 1.75 dB @ 10 GHz

Gain: 17 dB

P1dB Output Power: +19 dBm @ 5 GHz

Supply Voltage: +5V @ 55 mA Die Size: 2.64 x 1.64 x 0.1 mm

### **General Description**

The HMC-ALH444 is a GaAs MMIC HEMT Low Noise Wideband Amplifier die which operates between 1 and 12 GHz. The amplifier provides 17 dB of gain, 1.5 dB noise figure and +19 dBm of output power at 1 dB gain compression while requiring only 55 mA from a +5V supply voltage.

### Electrical Specifications\*, $T_A = +25^{\circ} \text{ C}$ , Vdd = +5V

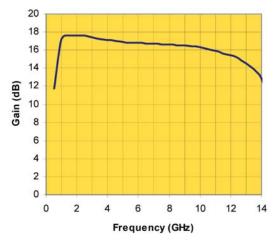
Parameter	Min.	Тур.	Max.	Units
Frequency Range		1 - 12		GHz
Gain	15	17		dB
Gain Variation over Temperature		0.02		dB/°C
Noise Figure		1.5	2	dB
Input Return Loss		10		dB
Output Return Loss		14		dB
Output IP3		28		dBm
Output Power for 1 dB Compression		19		dBm
Supply Current (Idd) (Vdd = 5V, Vgg1 = -0.5V Typ., Vgg2 = 1.5V Typ)		55		mA

<sup>\*</sup>Unless otherwise indicated, all measurements are from probed die

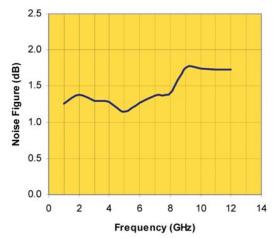


# GaAs HEMT MMIC LOW NOISE AMPLIFIER, 1 - 12 GHz

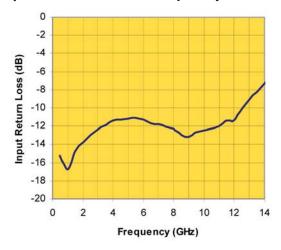
# Linear Gain vs. Frequency



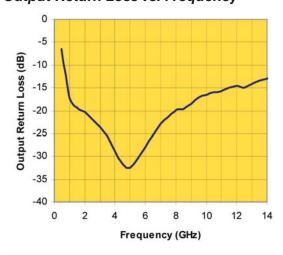
# Noise Figure vs. Frequency



#### Input Return Loss vs. Frequency



### **Output Return Loss vs. Frequency**



Note: Measured Performance Characteristics (Typical Performance at 25°C) Vd=5 V, Vg2=1.5 V, Id=55 mA



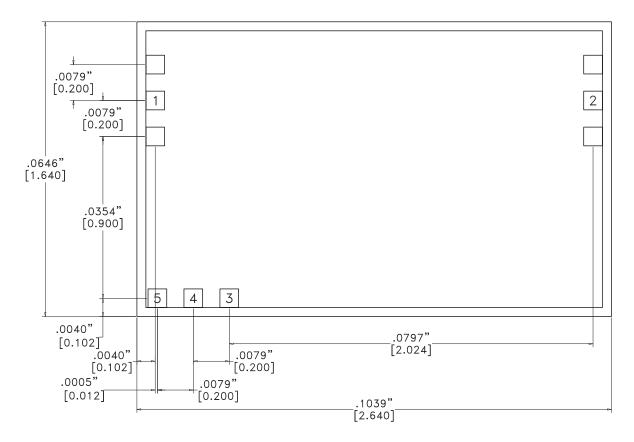
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# **Absolute Maximum Ratings**

Drain Bias Voltage	+5.5 Vdc	
RF Input Power	12 dBm	
Gate Bias Voltage Vgg1	-1 to 0.3 Vdc	
Gate Bias Voltage Vgg2	0 to 2.5 Vdc	
Channel Temperature	180 °C	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-55 to +85 °C	



### **Outline Drawing**



#### NOTES

- 1. ALL DIMENSIONS ARE IN INCHES [MM].
- 2. TYPICAL BOND PAD IS .004" SQUARE.
- 3. BACKSIDE METALLIZATION: GOLD.
- 4. BACKSIDE METAL IS GROUND.
- 5. BOND PAD METALLIZATION: GOLD.
- 6. CONNECTION NOT REQUIRED FOR UNLABELED BOND PADS.
- 7. OVERALL DIE SIZE ±.002"